RF power transistor the LdmoST family

Technical Literature

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SD57030

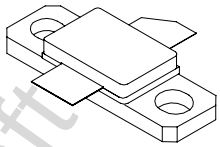
RF power transistor the LdmoST family

Features

- Excellent thermal stability
- Common source configuration
- P_{OUT} = 30W with 13dB gain @ 945MHz
- BeO free package
- Internal input matching
- In compliance with the 2002/95/EC european directive

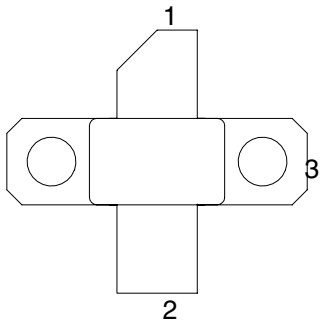
Description

The SD57030 is a common source N-channel enhancement-mode lateral Field-Effect RF power transistor designed for broadband commercial and industrial applications at frequencies up to 1.0 GHz. The SD57030 is designed for high gain and broadband performance operating in common source mode at 28 V. It is ideal for base station applications requiring high linearity.



M243
Epoxy sealed

Figure 1. Pin connection



1. Drain
2. Gate
3. Source

Table 1. Device summary

Order code	Package	Branding
SD57030	M243	SD57030

Contents

1 Electrical data

1.1 Maximum ratings

Table 1. Absolute maximum ratings (T_{CASE} = 25°C)

Symbol	Parameter	Value	Unit
$V_{(BR)DSS}$	Drain-Source voltage	65	V
V_{DGR}	Drain-Gate voltage (R_{GS} = 1 MΩ)	65	V
V_{GS}	Gate-Source voltage	+ 20	V
I_D	Drain current	4	A
P_{DISS}	Power dissipation (@ Tc = 70°C)	74	W
Tj	Max. operating junction temperature	200	°C
T_{STG}	Storage temperature	-65 to + 200	°C

1.2 Thermal data

Table 2. Thermal data

Symbol	Parameter	Value	Unit
R_{thJC}	Junction - case thermal resistance	1.75	°C/W

2 Electrical characteristics

T_{CASE} = +25 °C

2.1 Static

Table 3. Static (per section)

Symbol	Test conditions			Min	Typ	Max	Unit
$V_{(BR)DSS}$	V_{GS} = 0 V	I_{DS} = 10 mA		65			V
I_{DSS}	V_{GS} = 0 V	V_{DS} = 28 V				1	µA
I_{GSS}	V_{GS} = 20 V	V_{DS} = 0 V				1	µA
$V_{GS(Q)}$	V_{DS} = 28 V	I_D = 50 mA		2.0		5.0	V
$V_{DS(ON)}$	V_{GS} = 10 V	I_D = 3 A			1.3		V
G_{FS}	V_{DS} = 10 V	I_D = 3 A			1.8		mho
C_{ISS}(1)	V_{GS} = 0 V	V_{DS} = 28 V	f = 1 MHz		58		pF
C_{OSS}	V_{GS} = 0 V	V_{DS} = 28 V	f = 1 MHz		34		pF
C_{RSS}	V_{GS} = 0 V	V_{DS} = 28 V	f = 1 MHz		2.7		pF

1. Includes Internal Input Moscap.

2.2 Dynamic

Table 4. Dynamic

Symbol	Test conditions				Min	Typ	Max	Unit
P_{OUT}	V_{DD} = 28 V	I_{DQ} = 50 mA		f = 945 MHz	30			W
G_{PS}	V_{DD} = 28 V	I_{DQ} = 50 mA	P_{OUT} = 30 W	f = 945 MHz	13	15		dB
h_D	V_{DD} = 28 V	I_{DQ} = 50 mA	P_{OUT} = 30 W	f = 945 MHz	50	60		%
Load mismatch	V_{DD} = 28 V All phase angles	I_{DQ} = 50 mA	P_{OUT} = 28 W	f = 945 MHz	10:1			VSWR

3 Typical performance (CW)

Figure 2. Output power vs input power

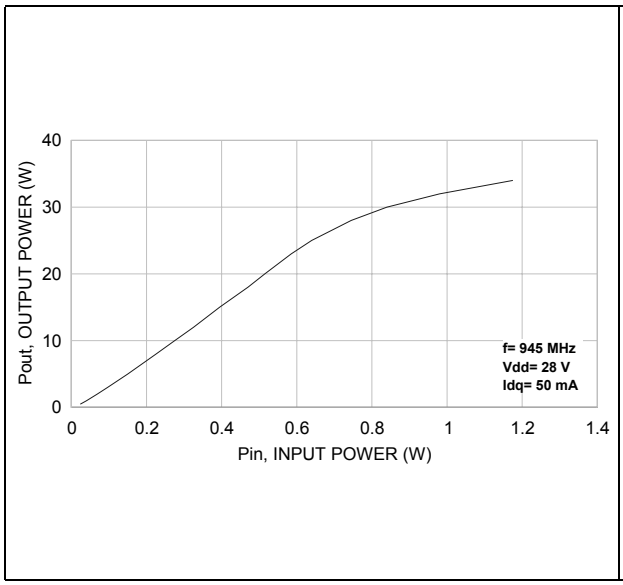


Figure 3. Power gain and efficiency vs output power

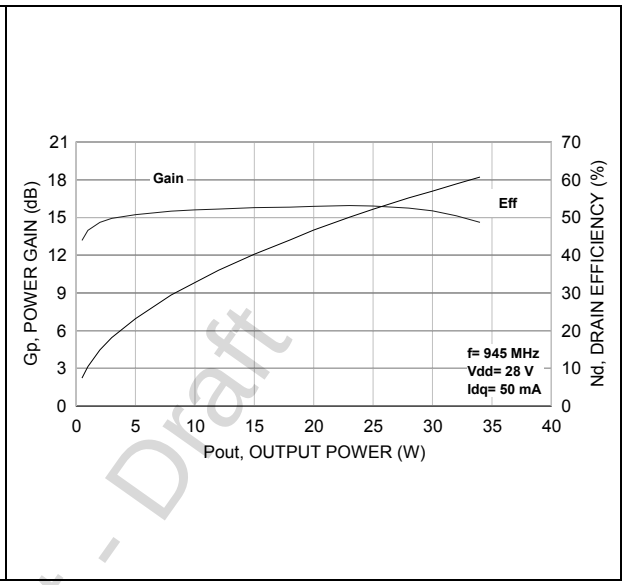


Figure 4. Output power vs gate source voltage

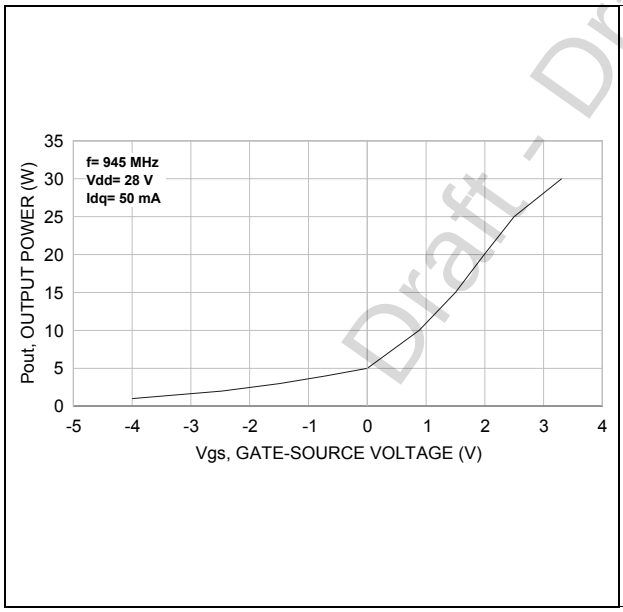
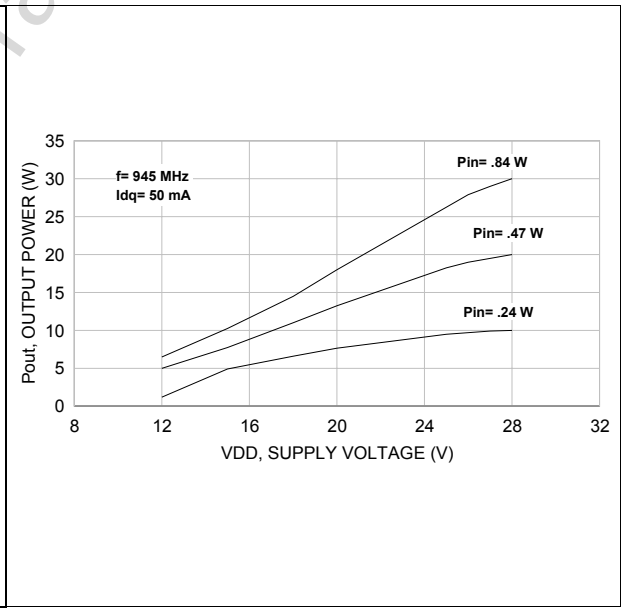
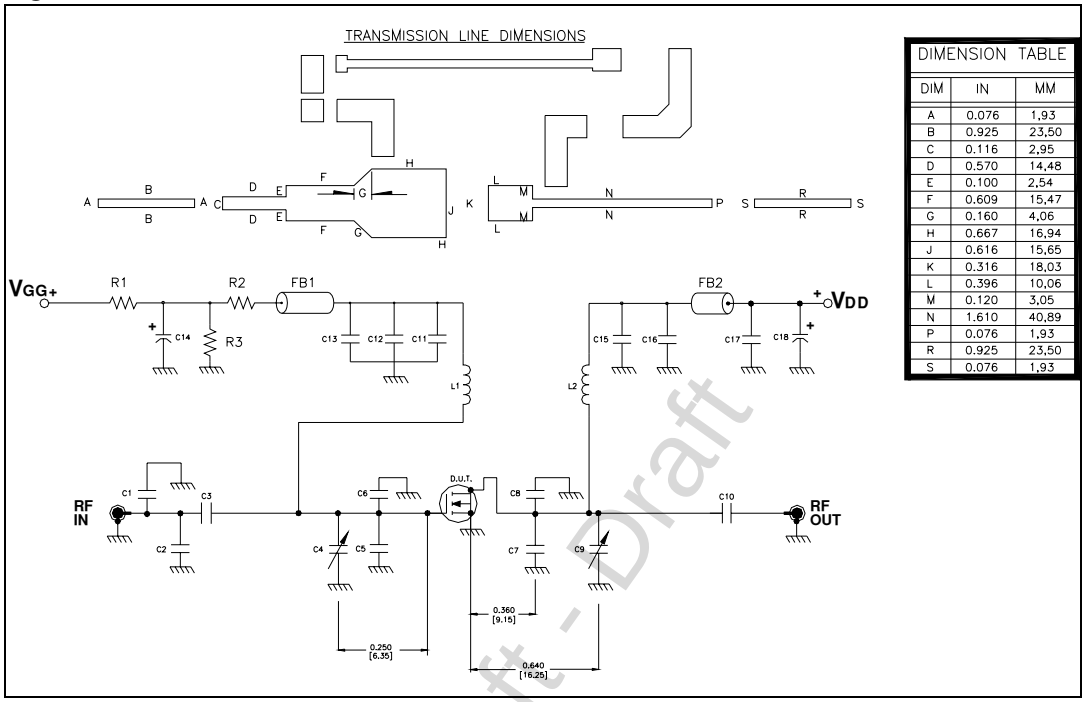


Figure 5. Output power vs supply voltage



4 Test circuit

Figure 6. Test circuit schematic



1 *Dimensions at component symbols are reference for component placement.*

2 *Gap between ground & transmission line = 0.056 [1.42] +0.002 [0.05] -0.000 [0.00] typ.*

3 *Dimensions of input and output component from edge of transmission lines.*

Table 5. Test circuit component part list

Component	Description
C19	200 µF / 63V ALLUMINIUM ELECTROLYTIC RADIAL LEAD CAPACITOR
C18, C14	0.1 µF / 500V SURFACE MOUNT CERAMIC CHIP CAPACITOR
C17	100 pF ATC 100B SURFACE MOUNT CERAMIC CHIP CAPACITOR
C16, C12, C11,C1	47 pF ATC 100B SURFACE MOUNT CERAMIC CHIP CAPACITOR
C15	10 µF / 50V ALUMINIUM ELECTROLYTIC RADIAL LEAD CAPACITOR
C13	100 pF ATC 700B SURFACE MOUNT CERAMIC CHIP CAPACITOR
C9, C2	0.8-8.0 pF GIGA TRIM VARIABLE CAPACITOR
C8	6.2 pF ATC 100B SURFACE MOUNT CERAMIC CHIP CAPACITOR
C7, C6, C5 ,C4	10 pF ATC 100B SURFACE MOUNT CERAMIC CHIP CAPACITOR
C3	3 pF ATC 100B SURFACE MOUNT CERAMIC CHIP CAPACITOR
R3	120 0-IM, 2W SURFACE MOUNT CERAMIC CHIP CAPACITOR
R2	4.7 M OHM 1W SURFACE MOUNT CERAMIC CHIP CAPACITOR
R1	18 K OHM, 1W SURFACE MOUNT CERAMIC CHIP CAPACITOR
FB2, FB1	SHIELD BEAD SURFACE MOUNT EMI
L2, L1	INDUCTOR, 5 TURNS AIR WOUND #22AWG, ID=0.059[1.49], NYLON COATED MAGNET WIRE
PCB	WOVEN FIBERGLASS REINFORCED PTFE 0.080” THK, εr=2.55, 2 Oz EDCu BOTH SIDE

5 Text circuit layout

Figure 7. Test fixture

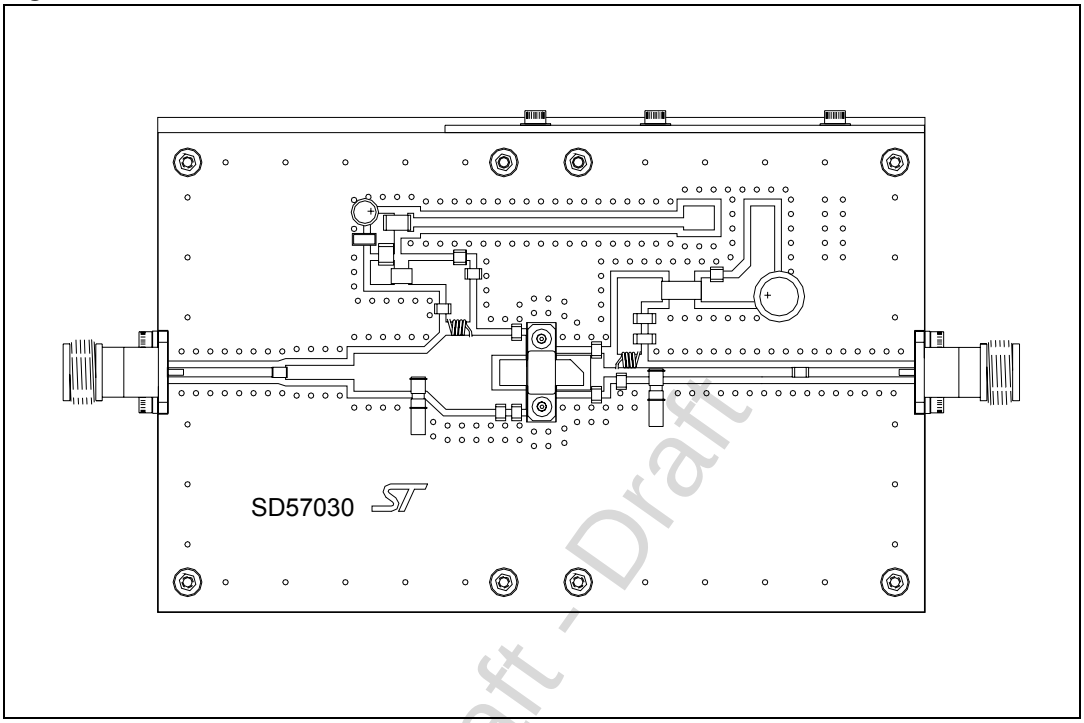
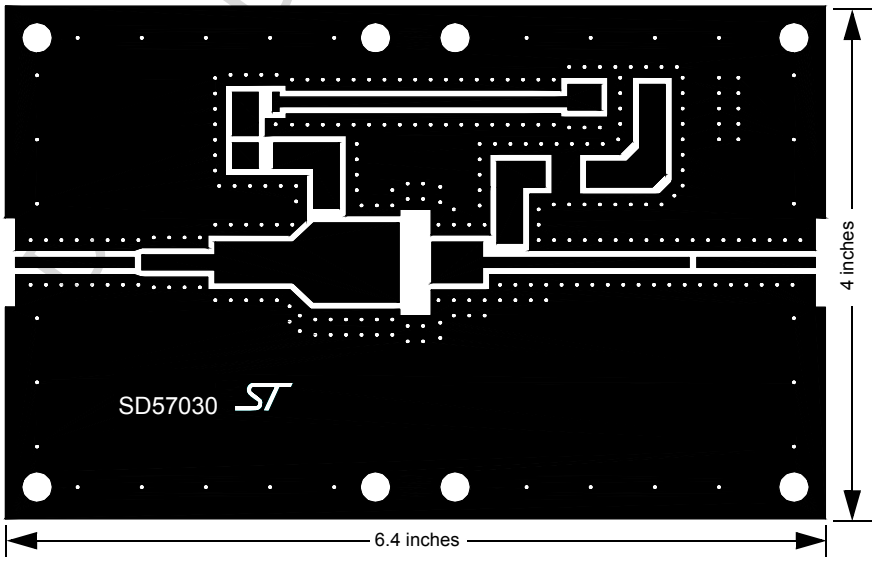


Figure 8. Test circuit photomaster

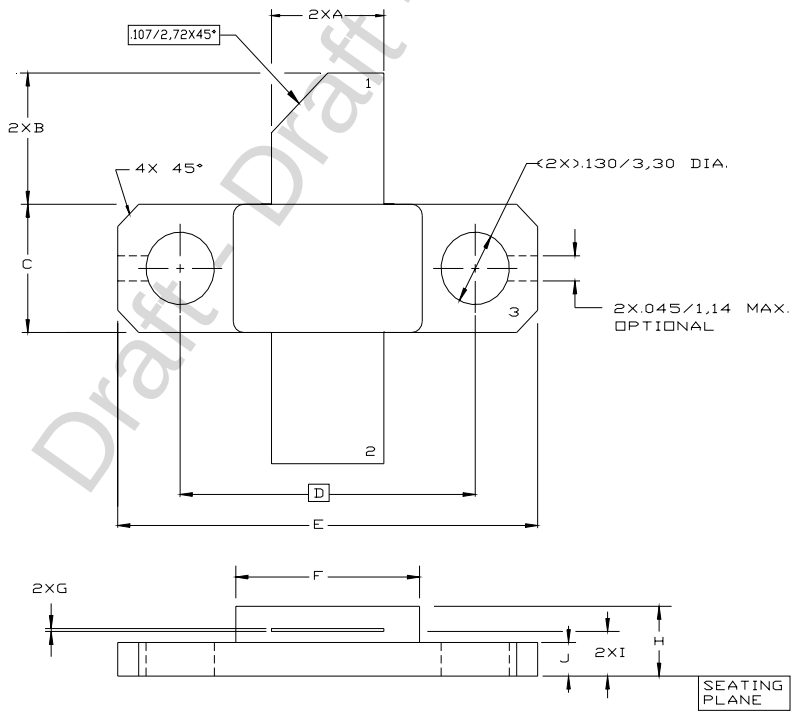


6 Package mechanical data

Table 6. M243 (.230 x .360 2L N/HERM W/FLG) mechanical data

Dim.	mm.			Inch		
	Min	Typ	Max	Min	Typ	Max
A	5.21		5.72	0.205		0.225
B	5.46		6.48	0.215		0.255
C	5.59		6.10	0.220		0.240
D		14.27			0.562	
E	20.07		20.57	0.790		0.810
F	8.89		9.40	0.350		0.370
G	0.10		0.15	0.004		0.006
H	3.18		4.45	0.125		0.175
I	1.83		2.24	0.072		0.088
J	1.27		1.78	0.050		0.070

Figure 9. Package dimensions



Controlling dimension: Inches 1022142E

7 Revision history

Table 7. Document revision history

Date	Revision	Changes
24-Mar-2003	5	First Issue.
11-Jul-2007	6	Document reformatted, added lead free info
24-Aug-2007	7	Cover page title updated

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